

HAMAMATSU

FLAT PANEL TYPE MULTIANODE PHOTOMULTIPLIER TUBE ASSEMBLY H8500, H8500B

52 mm Square, Bialkali Photocathode, 12-stage,
8 × 8 Multianode, Small Dead Space, Fast Time Response

APPLICATIONS

- Small Animal Imaging
- Compact Gamma Camera
- Scinti-mammography
- 2D Radiation Monitor



Left: H8500, Right: H8500B

SPECIFICATIONS

GENERAL

Parameter		Description / Value	Unit
Spectral Response		300 to 650	nm
Peak Wavelength		420	nm
Photocathode Material		Bialkali	—
Window	Material	Borosilicate glass	—
	Thickness	1.5	mm
Dynode	Structure	Metal channel dynode	—
	Number of Stages	12	—
Number of Anode Pixels		64 (8 × 8 matrix)	—
Pixel Size / Pitch at Center		5.8 × 5.8 / 6.08	mm
Effective Area		49 × 49	mm
Dimensional Outline (W × H × D)		52 × 52 × 28	mm
Packing Density (Effective Area / External Size)		89	%
Weight		140 (H8500), 117 (H8500B)	g
Operating Ambient Temperature		0 to +50	°C
Storage Temperature		-15 to +50	°C

MAXIMUM RATINGS (Absolute Maximum Values)

Parameter	Value	Unit
Supply Voltage (Between Anode to Cathode)	-1100	V
Average Anode Output Current in Total	100	μA
Divider Current at -1100 V	180	μA

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CHARACTERISTICS (at 25 °C)

Parameter		Min.	Typ.	Max.	Unit
Cathode Sensitivity	Luminous ^(A)	50	60	—	μA/lm
	Blue Sensitivity Index (CS 5-58) ^(B)	8.0	9.5	—	—
	Quantum Efficiency at 420 nm	—	24	—	%
Anode Sensitivity	Luminous ^(C)	—	90	—	A/lm
Gain ^(C)		0.5×10^6	1.5×10^6	—	—
Anode Dark Current per Channel ^(D)		—	0.1	—	nA
Anode Dark Current in Total ^(D)		—	6	50	nA
Time Response ^(E)	Rise Time ^(F)	—	0.8	—	ns
	Transit Time ^(G)	—	6	—	ns
	Transit Time Spread (FWHM) ^(H)	—	0.4	—	ns
Pulse Linearity per Channel ($\pm 2\%$ deviation)		—	1	—	mA
Uniformity (Condition Figure 3)		—	1: 2	1: 4	—
Cross-talk		—	3	—	%

NOTES

- (A): The light source is a tungsten filament lamp operated at a distribution temperature of 2856 K. Supply voltage is 150 volts between the cathode and all other electrodes connected together as anode.
- (B): The value is cathode output current when a blue filter (corning CS 5-58 polished to 1/2 stock thickness) is interposed between the light source and the tube under the same condition as Note (A).
- (C): Measured with the same light source as Note (A) and with the anode-to-cathode supply voltage and voltage distribution ratio shown in Table 1 below.
- (D): Measured with the same supply voltage and voltage distribution ratio as Note (C) after 30 minute storage in darkness.
- (E): Those are test data when a signal from a central channel of 64 anodes is used, while all photocathode are illuminated by pulsed light source.
- (F): The rise time is the time for the output pulse to rise from 10 % to 90 % of the peak amplitude when the whole photocathode is illuminated by a delta function light pulse.
- (G): The electron transit time is the interval between the arrival of delta function light pulse at the entrance window of the tube and the time when the anode output reaches the peak amplitude. In measurement, the whole photocathode is illuminated.
- (H): Also called transit time jitter. This is the fluctuation in electron transit time between individual pulses in the single photoelectron event, and defined as the FWHM of the frequency distribution of electron transit time.

Table 1: Voltage Distribution Ratio and Supply Voltage

Electrodes	K	Dy1	Dy2	Dy3	Dy4	Dy5	Dy6	Dy7	Dy8	Dy9	Dy10	Dy11	Dy12	GR	P
Distribution Ratio	1	1	1	1	1	1	1	1	1	1	1	1	1	0.9	0.1

Supply Voltage: -1000 V, K: Cathode, Dy: Dynode, GR: Guard Ring P: Anode

Figure 1: Typical Spectral Response

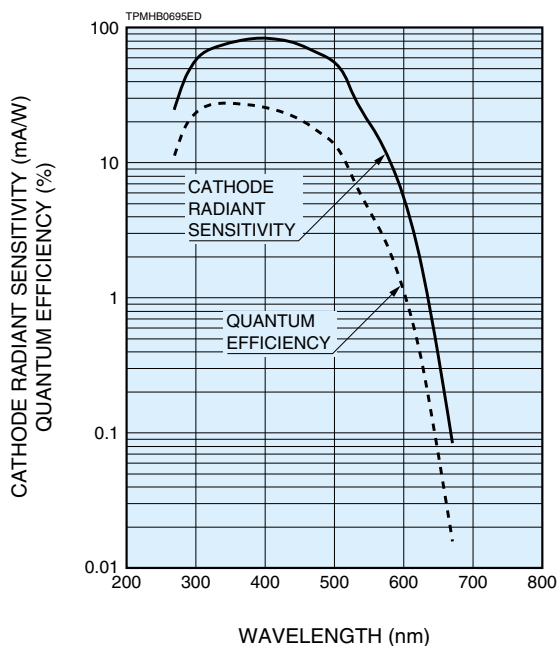


Figure 2: Typical Gain Characteristics

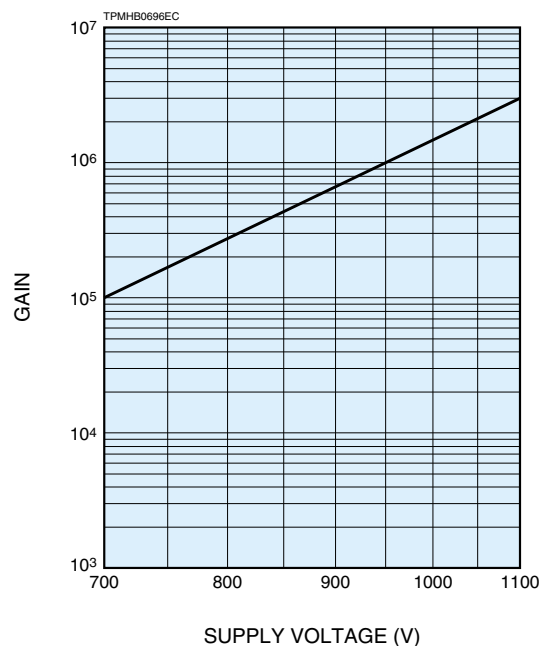
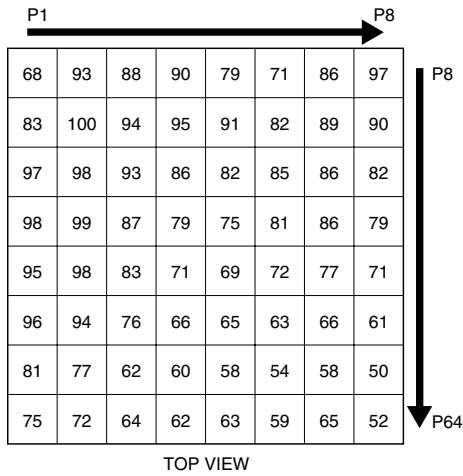


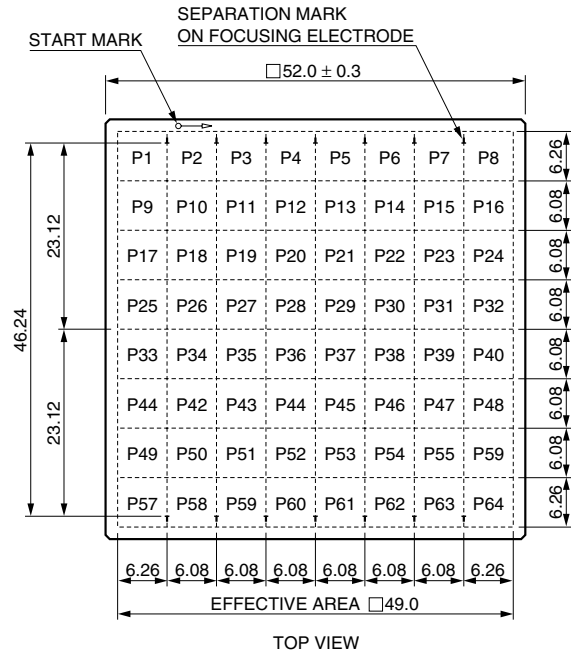
Figure 3: Anode Uniformity (Example)



SUPPLY VOLTAGE: -1000 V
 LIGHT SOURCE: TUNGSTEN LAMP with BLUE FILTER (DC LIGHT)
 SPOT ILLUMINATION (APERTURE SIZE): 6 mm square on each channel

TPMH0697EC

Figure 4: Anode Matrix and Separation Mark

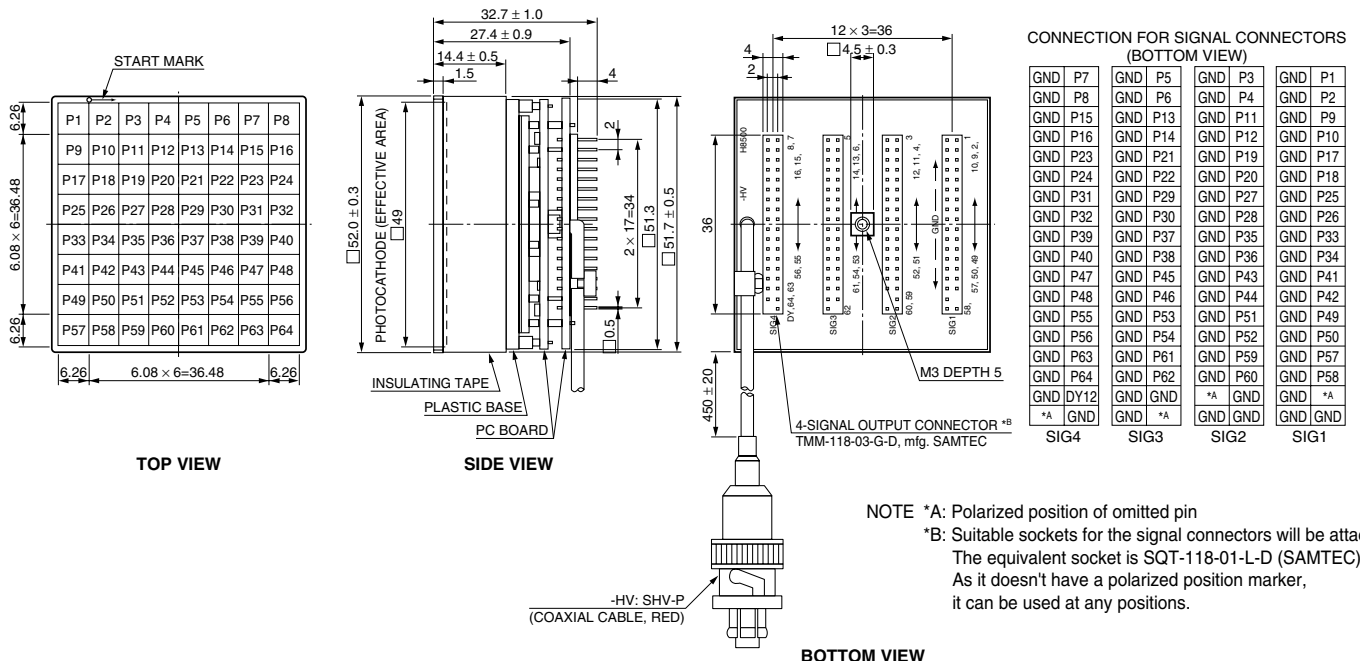


The start mark and the separation marks are put on an electrode plate inside.

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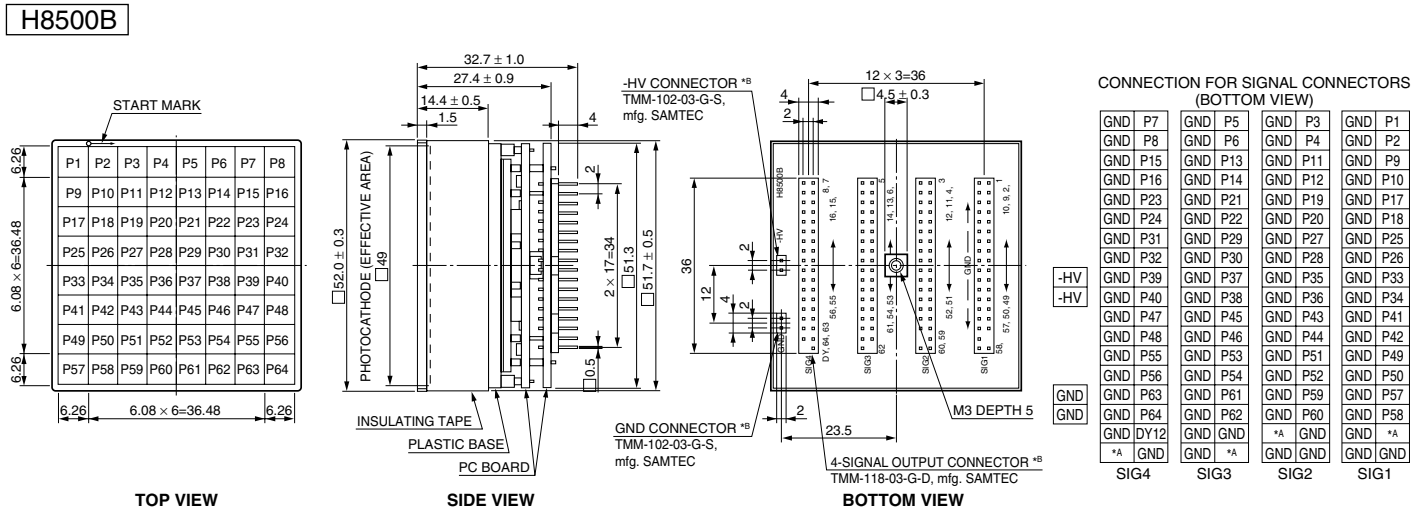
Figure 5: Dimensional Outline (Unit: mm)

H8500



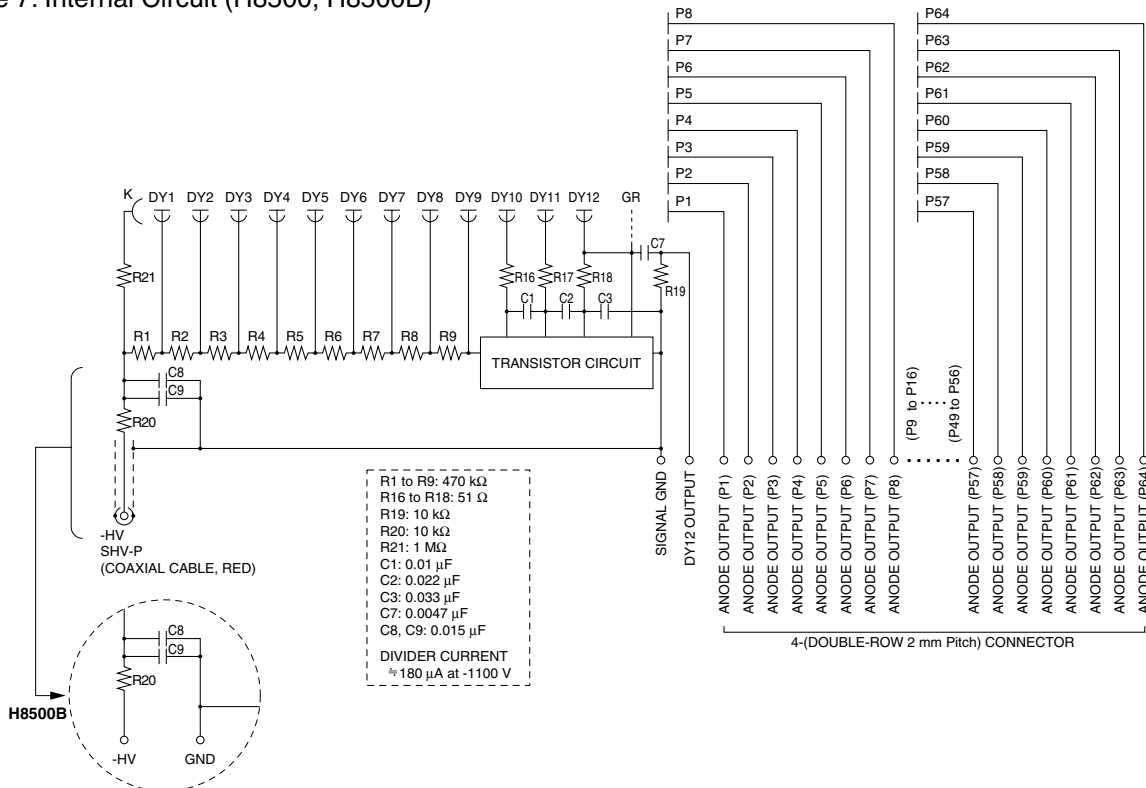
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Figure 6: Dimensional Outline (Unit: mm)



NOTE *A: Polarized position of omitted pin
 *B: Suitable sockets for the signal connectors will be attached.
 The equivalent socket for signal output is SQT-118-01-L-D (SAMTEC).
 The equivalent socket for -HV, GND is SQT-102-01-L-S (SAMTEC).
 As it doesn't have a polarized position marker, it can be used at any positions.

Figure 7: Internal Circuit (H8500, H8500B)



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WEB SITE www.hamamatsu.com

HAMAMATSU PHOTONICS K.K., Electron Tube Division

314-5, Shimokanzo, Iwata City, Shizuoka Pref., 438-0193, Japan, Telephone: (81)539/62-5248, Fax: (81)539/62-2205

U.S.A.: Hamamatsu Corporation: 360 Foothill Road, P. O. Box 6910, Bridgewater, N.J. 08807-0910, U.S.A., Telephone: (1)908-231-0960, Fax: (1)908-231-1218 E-mail: usa@hamamatsu.com

Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49)8152-375-0, Fax: (49)8152-2658 E-mail: info@hamamatsu.de

France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: (33)1 69 53 71 00, Fax: (33)1 69 53 71 10 E-mail: infos@hamamatsu.fr

United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road Welwyn Garden City Hertfordshire AL7 1BW, United Kingdom, Telephone: 44-(0)1707-294888, Fax: 44(0)1707-325777 E-mail: info@hamamatsu.co.uk

North Europe: Hamamatsu Photonics Norden AB: Smidesvägen 12, SE-171-41 SOLNA, Sweden, Telephone: (46)8-509-031-00, Fax: (46)8-509-031-01 E-mail: info@hamamatsu.se

Italy: Hamamatsu Photonics Italia: S.R.L.: Strada della Moia, 1/E, 20020 Arese, (Milano), Italy, Telephone: (39)02-935 81 733, Fax: (39)02-935 81 741 E-mail: info@hamamatsu.it

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